

DESCRIPTION

The ULN2803/2804 series are high-voltage, high-current darlington arrays comprised of eight NPN darlington

pairs. All units feature integral clamp diodes for switching inductive loads.

FEATURES

- Output current 500mA
- High Sustaining Voltage 50V Min.
- Output Clamp Diode
- Inputs Compatible With Various Types of Logic

Type	Input Resistor	Designation
ULN2803	2.7KΩ	TTL, 5V C - MOS
ULN2804	10.5KΩ	6 ~ 15V P - MOS, C - MOS

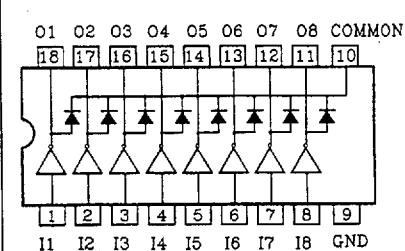
MAXIMUM RATING(T_a=25°C unless otherwise)

Characteristic	Symbol	Rating	Unit
Output Sustaining Voltage	V _{CE(SUS)}	50	V
Output Current	I _{OUT}	500	mA
Input Voltage	V _{IN}	-0.5~+30	V
Input Current	I _{IN}	25	mA
Clamp Reverse Voltage	V _R	50	V
Diode Forward Current	I _F	500	mA
GND Terminal Current	I _{GND}	3.2	A
Power Dissipation	P _D	1.47	W
Operating Temperature	T _{opr}	-40~85	°C
Storage Temperature	T _{stg}	-55~150	°C

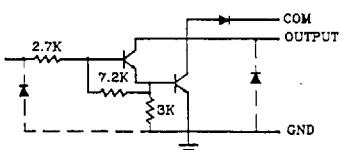
18 DIP



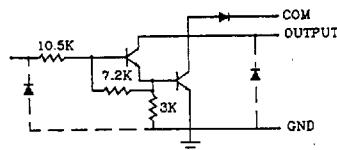
PIN CONNECTION (TOP VIEW)



ULN2803



ULN2804



RECOMMENDED OPERATING CONDITIONS(T_a=-40~85°C)

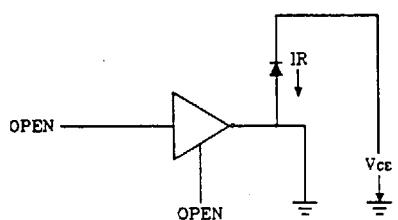
CHARACTERISTIC	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Output Sustaining Voltage	V _{CE(SUS)}		0	-	50	V
Output Current	I _{OUT}	T _{PW} =25mS, DF=8%, 8 Circuits T _{PW} =25mS, DF=25% 8 Circuits	0	-	400	mA
			0	-	200	
Input Voltage	V _{IN}		0	-	30	V
Clamp Diode Reverse Voltage	V _R		-	-	50	V
Clamp Diode Forward Current	I _F		-	-	400	mA
Power Dissipation	P _D		-	-	0.52	W

ELECTRICAL CHARACTERISTICS(T_a=25°C unless otherwise noted)

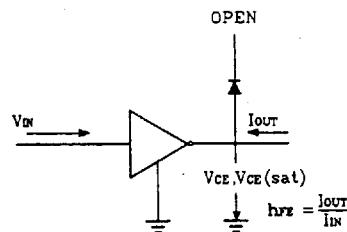
CHARACTERISTIC	SYMBOL	TEST CIRCUIT	CONDITION	MIN.	TYP.	MAX.	UNIT
Output leak Current ULN2804	I _{CEx}	1	V _{CE} =50V, T _a =25°C	-	-	50	
			V _{CE} =50V, T _a =85°C	-	-	100	μA
			V _{CE} =50V, V _N =1V	-	-	500	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	2	I _{OUT} =350mA, I _B =500μA	-	1.3	1.6	
			I _{OUT} =200mA, I _B =350μA	-	1.1	1.3	V
			I _{OUT} =100mA, I _B =250μA	-	0.9	1.1	
Input Current ULN2803 ULN2804	I _{IN(on)}	3	V _N =3.85V	-	0.93	1.35	
			V _N =5V	-	0.35	0.5	mA
Input Voltage	V _{IN(OFF)}	4	V _N =12V	-	1.0	1.45	
			I _{OUT} =500μA, T _a =85°C	50	65	-	μA
			V _{CE} =2V, I _{OUT} =200mA	-	-	2.4	
			V _{CE} =2V, I _{OUT} =250mA	-	-	2.7	V
			V _{CE} =2V, I _{OUT} =300mA	-	-	3.0	
DC Current Transistor Ratio	h _{FE}	5	V _{CE} =2V, I _{OUT} =125mA	-	-	5.0	
			V _{CE} =2V, I _{OUT} =200mA	-	-	6.0	
Clamp Diode Reverse Current ULN2804	I _E	6	V _{CE} =2V, I _{OUT} =275mA	-	-	7.0	
			V _{CE} =2V, I _{OUT} =350mA	-	-	8.0	V
Clamp Diode Forward Voltage	V _F	7	V _{CE} =2V, I _{OUT} =350mA	1000	-	-	
			V _R =50V, T _a =25°C	-	-	50	μA
Input Capacitance	C _{IN}	8	V _R =50V, T _a =85°C	-	-	100	
			I _F =350mA	-	-	2.0	pF
Turn-On Delay	t _{ON}	8	V _{OUT} =50V, R _L =163Ω	-	0.1	-	μS
			C _L =15 pF	-	0.2	-	
Turn-Off Delay	t _{OFF}						

TEST CIRCUIT

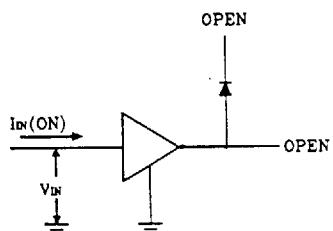
1. I_{CEX}



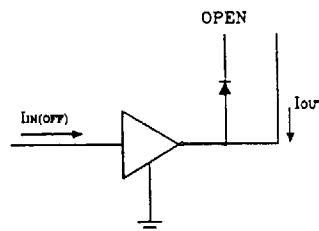
2. $V_{CE(sat)}, h_{FE}$



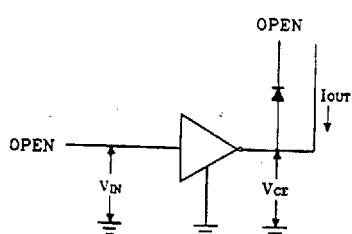
3. $I_{IN(ON)}$



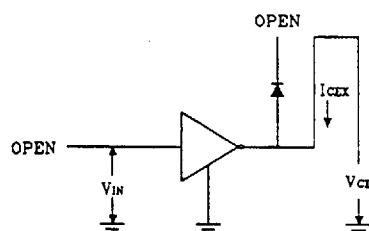
4. $I_{IN(OFF)}$



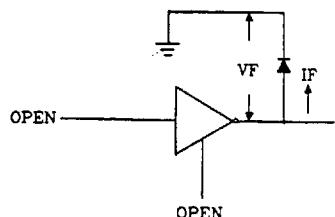
5. $V_{IN(ON)}$



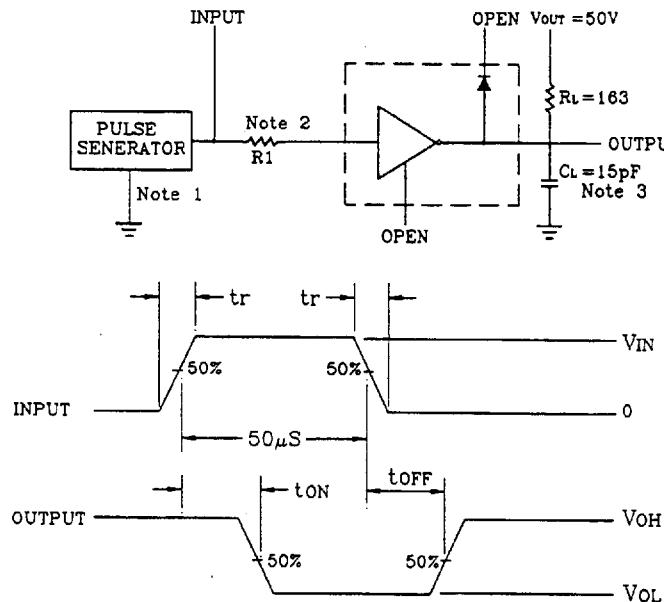
6. I_R



7. V_F



8. t_{ON} , t_{OFF}



Notes: 1. Pulse Width 50 μ s, Duty Cycle 10%

Output Impedance 50 Ω

$t_r \leq 5\text{ns}$, $t_f \leq 10\text{ns}$

2. See below

Input Conditions

TYPE NUMBER	R _I	V _{IH}
ULN2803	0	3V
ULN2804	0	8V

3. C_L includes prob and jig capacitance.

